

Surface Mount General Purpose Silicon Rectifiers		Reverse Voltage - 50 to 1000 V Forward Current - 1 A																																																																																																																						
<u>SMA</u> <table> <thead> <tr> <th>PIN</th><th>DESCRIPTION</th></tr> </thead> <tbody> <tr> <td>1</td><td>Cathode</td></tr> <tr> <td>2</td><td>Anode</td></tr> </tbody> </table>  Top View Marking Code: M1~M7 Simplified outline SMA and symbol		PIN	DESCRIPTION	1	Cathode	2	Anode	Features <ul style="list-style-type: none"> For surface mounted applications Low profile package Glass Passivated Chip Junction Easy to pick and place Lead free in comply with EU RoHS 2011/65/EU directives Mechanical Data <ul style="list-style-type: none"> Case: SMA Terminals: Solderable per MIL-STD-750, Method 2026 Approx. Weight: 0.055g / 0.002oz 																																																																																																																
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Maximum Ratings and Electrical characteristics Ratings at 25 °C ambient temperature unless otherwise specified. Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.																																																																																																																								
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(1) Measured at 1 MHz and applied reverse voltage of 4 V D.C (2) P.C.B. mounted with 1.0 X 1.0" (2.54 X 2.54 cm) copper pad areas.																																																																																																																								

Fig.1 Forward Current Derating Curve

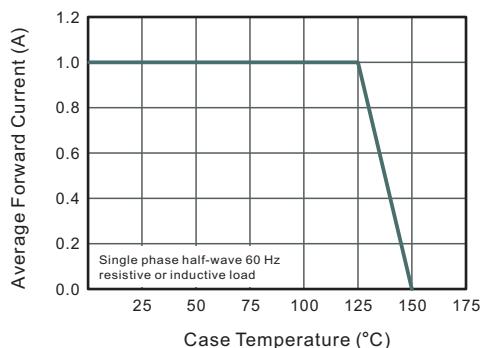


Fig.2 Typical Instantaneous Reverse Characteristics

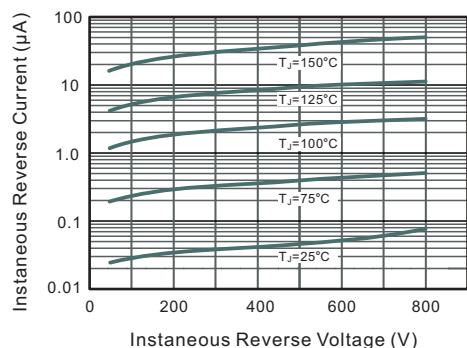


Fig.3 Typical Forward Characteristic

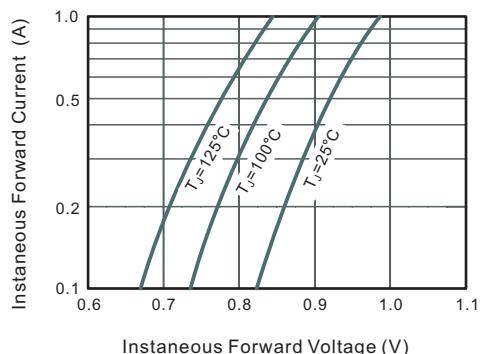


Fig.4 Typical Junction Capacitance

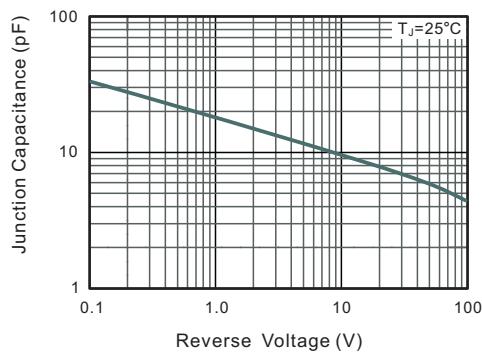
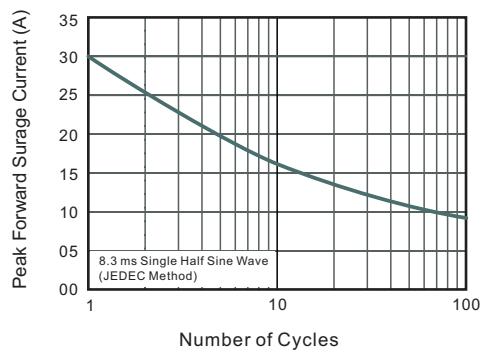


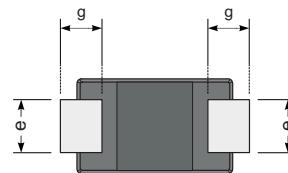
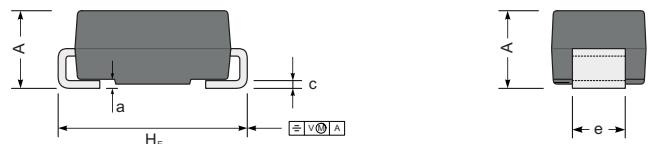
Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



PACKAGE OUTLINE

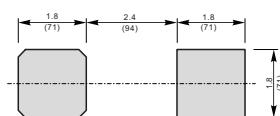
Plastic surface mounted package; 2 leads

SMA



UNIT		A	D	E	H _E	c	e	g	a
mm	max	2.2	4.5	2.7	5.2	0.31	1.6	1.5	0.3
	min	1.9	4.0	2.3	4.7	0.15	1.3	0.9	
mil	max	87	181	106	205	12	63	59	12
	min	75	157	91	185	6	51	35	

The recommended mounting pad size



Unit : $\frac{\text{mm}}{(\text{mil})}$

Marking

Type number	Marking code
M1	M1
M2	M2
M3	M3
M4	M4
M5	M5
M6	M6
M7	M7

单击下面可查看定价，库存，交付和生命周期等信息

[>>DIOS\(迪恩思\)](#)